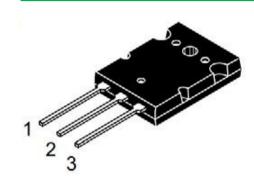


BIPOLAR POWER TRANSISTORS 15 AMP, 230 VOLT,150 WATT

TO-3PL



Complementary ThermalTrak™ Transistors

The ThermalTrak family of devices has been designed to eliminate thermal equilibrium lag time and bias trimming in audio amplifier applications. They can also be used in other applications as transistor die protection devices.

Features

- Thermally Matched Bias Diode
- · Instant Thermal Bias Tracking
- Absolute Thermal Integrity
- · High Safe Operating Area
- Pb-Free Packages are Available*

Benefits

- Eliminates Thermal Equilibrium Lag Time and Bias Trimming
- Superior Sound Quality Through Improved Dynamic Temperature Response
- · Significantly Improved Bias Stability
- Simplified Assembly
 - ♦ Reduced Labor Costs
 - ♦ Reduced Component Count
- High Reliability

PNP

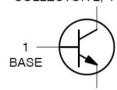
COLLECTOR 2, 4



EMITTER 3

NPN





EMITTER 3

Applications

- High-End Consumer Audio Products
 - ♦ Home Amplifiers
 - ♦ Home Receivers
- Professional Audio Amplifiers
 - ◆ Theater and Stadium Sound Systems
 - ♦ Public Address Systems (PAs)

ORDERING INFORMATION

Device	Package
SJB7150	TO-3PL
SJB6150	TO-3PL



MAXIMUM RATINGS (TJ = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	VCEO	230	Vdc
Collector-Base Voltage	VCBO	230	Vdc
Emitter-Base Voltage	VEBO	5	Vdc
Collector-Emitter Voltage - 1.5 V	VCEX	230	Vdc
Collector Current- Continuous	IC	15	Adc
− Peak (Note 1)		25	
Base Current - Continuous	lв	1.5	Adc
Total Power Dissipation @ TC = 25 °C	PD	150	W
Operating and Storage Junction Temperature Range	TJ,Tstg	- 55 to +150	°C
Average Rectified Forward Current	lF(AV)	1	А

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	Rqjc	0.833	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Pulse Test: Pulse Width = 5 ms, Duty Cycle < 10%.

ATTRIBUTES

	Characteristic	Value
ESD Protection	Human Body Model Machine Model	>8000 V > 400 V
Flammability Rating		UL 94 V-0 @ 0.125 in



ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Emitter Sustaining Voltage	VCEO(sus)	230	-	Vdc
(IC = 100 mAdc, IB = 0)		230		
Collector Cutoff Current	Ісво	_	10	mAdc
(VCB = 230 Vdc, IE = 0)				
Emitter Cutoff Current	IEBO	_	5	mAdc
(VEB = 5 Vdc, IC = 0)			3	III/GC
ON CHARACTERISTICS				
DC Current Gain				
(IC = 500 mAdc, VCE = 5 Vdc)	h _{FE}	80	160	
(IC = 1 Adc, VCE = 5 Vdc)		80	160	
(IC = 3 Adc, VCE = 5 Vdc)		80	160	
Collector-Emitter Saturation Voltage	VCE(sat)		3	Vdc
(IC = 8 Adc, IB = 0.8 Adc)	VOL(Sat)	_		
Base-Emitter On Voltage	VCE(on)	-	1.5	Vdc
(IC =7 Adc, V CE = 5 Vdc)	5=(***)			
DYNAMIC CHARACTERISTICS				
Current-Gain - Bandwidth Product	£	00	-	MHz
(IC = 1 Adc, VCE = 5 Vdc, ftest = 1 MHz)	f⊤	30		
Output Capacitance	Cob	-	400	pF
(VCB = 10 Vdc, IE = 0, ftest = 1 MHz)				
Maximum Instantaneous Forward Voltage (Note 2)				
(iF = 1.0 A, TJ = 25°C)	V F	1.1		V
(iF = 1.0 A, TJ = 150°C)		0.	0.93	
Maximum Instantaneous Reverse Current (Note 2)				
(Rated dc Voltage, TJ = 25°C)	İR	10 100		uA
(Rated dc Voltage, TJ = 150°C)				
Maximum Reverse Recovery Time	t _{rr}	1	00	ns
(iF = 1.0 A, di/dt = 50 A/ms)				

^{2.} Diode Pulse Test: Pulse Width = 300 ms, Duty Cycle v 2.0%.





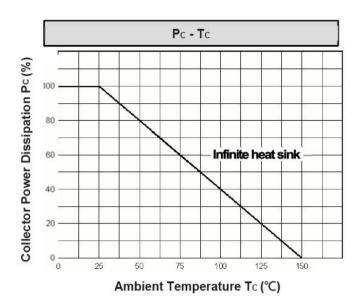


Figure 1. Power Derating

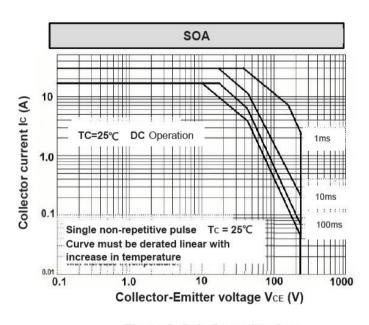


Figure 2. Safe Operating Area

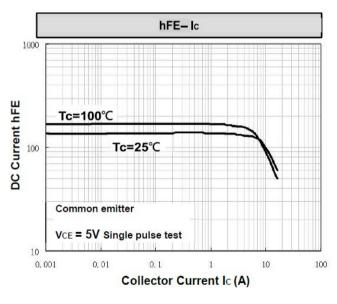


Figure 3.SJB6150 DC Current Gain

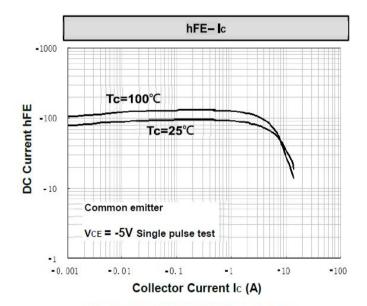


Figure 4. SJB7150 DC Current Gain





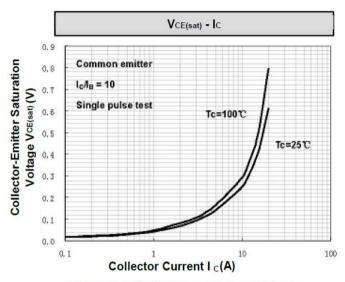


Figure 5. SJB6150 Base-Emitter Voltage

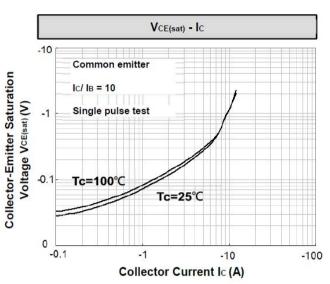


Figure 6. SJB7150 Base-Emitter Voltage

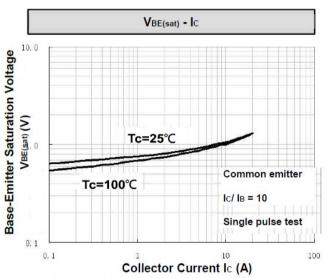


Figure 7. SJB6150 Saturation Voltage

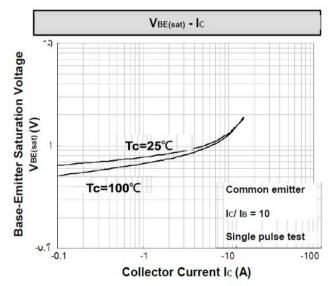


Figure 8. SJB7150 Saturation Voltage



PACKAGE DIMENSIONS

TO-3PL Unit: mm

